

RoHS

Specification ssc-szx05A0A

(Rev.06_111024)

S	SC	Customer
Drawn	Approval	Approval

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SEOUL SEMICONDUCTOR

SZX05A0A

Description

The Z-Power series is designed for high current operation and high flux output applications.

It incorporates state of the art SMD design and low thermal resistant material. The Z Power LED is ideal light sources for general illumination applications, custom designed solutions, automotive, large backlights and high performance torches.

Red



Green



Blue



Amber



SZX05A0A

Features

- Super high Flux output and high Luminance
- Designed for high current operation
- SMT solderable
- Lead Free product
- RoHS compliant

Applications

- Automotive interior / exterior lighting
- Automotive signal lighting
- Automotive forward lighting
- General Torch
- Architectural lighting
- Projector light source
- Traffic signals
- Task lighting
- Decorative / Pathway lighting
- Remote / Solar powered lighting

* The appearance and specifications of the product can be changed for improvement without notice.

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Notes :

- [1] All dimensions are in millimeters.
- [2] Scale : none
- [3] Undefined tolerance is ± 0.1 mm

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Characteristics of Z5 (Part No : SZR05A0A)

- Red

1-1 Electro-Optical characteristics at 350mA

Parameter	Symbol		Value		Unit
Parameter	Symbol	Min	Тур	Max	Unit
Luminous Flux ^[1]	Φ _V ^[2]	-	55	-	lm
Dominant Wavelength ^[3]	λ _D	-	625	-	nm
Forward Voltage [4]	V _F	-	2.4	-	V
Thermal resistance (J to S)	$R\theta_{J-S}$		7.0		K /W
View Angle	2⊝ 1⁄2		123		deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	700	mA
Reverse Voltage	V	5	V
Power Dissipation	P _d	2.1	W
Junction Temperature	Тj	125(@ $I_F \le 700 \text{mA}$)	٥C
Operating Temperature	T _{opr}	-40 ~ +100	٥C
Storage Temperature	T _{stg}	-40 ~ +100	٥C
ESD Sensitivity [5]	-	± 8,000V HBM	-

*Notes :

[1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.

[2] Φ_{V} is the total luminous flux output as measured with an integrating sphere.

[3] Dominant Wavelength is derived from the CIE 1931 Chromaticity diagram. A tolerance of ± 0.5 nm for dominant wavelength.

[4] Tolerance is $\pm 0.06V$ on forward voltage measurements

[5] A zener diode is included to protect the product from ESD.



SEOUL SEMICONDUCTOR

Characteristics of Z5 (Part No : SZG05A0A)

- Green

1-1 Electro-Optical characteristics at 350mA

Devementer	Symbol		Value		Unit
Parameter	Symbol	Min	Тур	Max	Unit
Luminous Flux ^[1]	Φ _V ^[2]	-	100	-	lm
Dominant Wavelength ^[3]	λ _D	-	525	-	nm
Forward Voltage [4]	V _F	-	3.3	-	V
Thermal resistance (J to S)	$R\theta_{J-S}$		10.0		K/W
View Angle	2⊖ 1⁄2		128		deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	700	mA
Reverse Voltage	V	5	V
Power Dissipation	P _d	2.8	W
Junction Temperature	Тj	145(@ $I_F \le 700 \text{mA}$)	٥C
Operating Temperature	T _{opr}	-40 ~ +100	٥C
Storage Temperature	T _{stg}	-40 ~ +100	٥C
ESD Sensitivity [5]	-	± 8,000V HBM	-

*Notes :

[1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.

[2] Φ_{V} is the total luminous flux output as measured with an integrating sphere.

[3] Dominant Wavelength is derived from the CIE 1931 Chromaticity diagram. A tolerance of ± 0.5 nm for dominant wavelength.

[4] Tolerance is ±0.06V on forward voltage measurements

[5] A zener diode is included to protect the product from ESD.



SEOUL SEMICONDUCTOR

Characteristics of Z5 (Part No : SZB05A0A)

- Blue

1-1 Electro-Optical characteristics at 350mA

Davamatar	Symbol		Value		Unit
Parameter	Symbol	Min	Тур	Max	Unit
Luminous Flux ^[1]	Φ _V ^[2]	-	28	-	lm
Dominant Wavelength ^[3]	λ _D	-	465	-	nm
Forward Voltage [4]	V _F	-	3.3	-	V
Thermal resistance (J to S)	$R\theta_{J-S}$		7.0		K /W
View Angle	2⊝ 1⁄2		128		deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	700	mA
Reverse Voltage	V	5	V
Power Dissipation	P _d	2.8	W
Junction Temperature	Τ _j	145(@ $I_F \le 700 \text{mA}$)	٥C
Operating Temperature	T _{opr}	-40 ~ +100	٥C
Storage Temperature	T _{stg}	-40 ~ +100	٥C
ESD Sensitivity [5]	-	± 8,000V HBM	-

*Notes :

[1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.

[2] Φ_{V} is the total luminous flux output as measured with an integrating sphere.

[3] Dominant Wavelength is derived from the CIE 1931 Chromaticity diagram. A tolerance of ± 0.5 nm for dominant wavelength.

[4] Tolerance is $\pm 0.06V$ on forward voltage measurements

[5] A zener diode is included to protect the product from ESD.



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Characteristics of Z5 (Part No : SZA05A0A)

- Amber

1-1 Electro-Optical characteristics at 350mA

Parameter	Symbol		Value		Unit
Parameter	Symbol	Min	Тур	Max	Unit
Luminous Flux ^[1]	Φ _V ^[2]	-	46	-	lm
Dominant Wavelength ^[3]	λ _D	-	592	-	nm
Forward Voltage [4]	V _F	-	2.3	-	V
Thermal resistance (J to S)	$R\theta_{J-S}$		9.0		K /W
View Angle	2⊝ 1⁄2		123		deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	700	mA
Reverse Voltage	V	5	V
Power Dissipation	P _d	2.1	W
Junction Temperature	Тj	125(@ $I_F \le 700 \text{mA}$)	٥C
Operating Temperature	T _{opr}	-40 ~ +100	٥C
Storage Temperature	T _{stg}	-40 ~ +100	٥C
ESD Sensitivity [5]	-	± 8,000V HBM	-

*Notes :

[1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.

[2] Φ_{V} is the total luminous flux output as measured with an integrating sphere.

[3] Dominant Wavelength is derived from the CIE 1931 Chromaticity diagram. A tolerance of ± 0.5 nm for dominant wavelength.

[4] Tolerance is $\pm 0.06V$ on forward voltage measurements

[5] A zener diode is included to protect the product from ESD.



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Forward Current Characteristics

Forward Voltage vs. Forward Current, Ta=25°C







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Forward Current vs Wavelength Shift, Ta=25℃



Junction Temperature Characteristics

Relative Light Output vs. Junction Temperature at IF=350mA



Color Spectrum T_A=25℃



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Radiation pattern





- Green



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- Blue





- Amber



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Maximum Forward Current vs. Ambient Temperature



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Luminous Flux

Rank	LF [lm]	Color	Condition
κ	8.5~ 11.0		
L	11.0~ 14.5		
М	14.5~ 19.0		
0	19.0~ 24.5		
Р	24.5~ 32.0		
Q	32.0~ 41.5		350mA
R	41.5~ 54.0		
S	54.0~ 70.0		
τ	70.0~ 91.0]
U	91.0~ 118.5		

Dominant Wavelength

Rank	DW [nm]	Сс	olor	Condition
BB1	453~ 460			
BB2	460~ 465			
BB3	465~ 470			
BB4	470~ 475			
GG1	518~ 525			
GG2	525~ 530			
GG3	530~ 535			350mA
AA 1	585~ 587.5			000111/1
AA2	587.5~ 590			
AA3	590~ 592.5			
AA 4	592.5~ 595			
RR1	618~ 625			
RR2	625~ 632			

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Forward Voltage

Rank	V _F [V]	Color	Condition
D	2.0~ 2.25		350mA
E	2.25~ 2.5		
F	2.5~ 2.75		
G	2.75~ 3.0		
Н	3.0~ 3.25		
1	3.25~ 3.5		
J	3.5~ 3.75		
K	3.75~ 4.0		

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Labeling



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Rank :	# 1 # 2 # 3
QUANTITY: 1000	
Lot No : #########	
SSC PART NUMBER : SZX05A0A	
SZX05A0A	

Rank

<u># 1# 2# 3</u>

- #1 : Luminous Flux : LF [lm]
- #2 : Dominant Wavelength : DW [nm]
- #3 : Forward Voltage : V_F [V]



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Emitter Carrier & Reel Packaging



NOTES:

- 1. 10 sprocket hole pitch cumulative tolerance ± 0.20
- 2. Camber not to exceed 1mm in 250mm
- 3. Material: Black conductive Polystyrene
- Ao and Bo measured on a plane 0.3mm above the bottom of the pocket
- Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
- Pocket center and pocket hole center must be same position.

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Packing









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Recommended solder pad



Notes :

- [1] All dimensions are in millimeters.
- [2] Scale : none
- [3] This drawing without tolerances are for reference only

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Reflow Soldering Conditions / Profile



* Caution

- 1. Reflow soldering should not be done more than one time.
- 2. Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- 3. Die slug is to be soldered.
- 4. When soldering, do not put stress on the LEDs during heating.
- 5. After soldering, do not warp the circuit board.
- 6. Recommend to use a convection type reflow machine with 7 ~ 8 zones.

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Precaution for use

Storage

To avoid the moisture penetration, we recommend storing Z Power LEDs in a dry box with a desiccant . The recommended storage temperature range is 5C to 30C and a maximum humidity of 50%.

• Use Precaution after Opening the Packaging

Use proper SMD techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Soldering should be done immediately after opening the package (within 24Hrs).
- b. Required conditions after opening the package
 - Sealing
 - Temperature : $5 \sim 40^{\circ}$ C Humidity : less than 30%
- c. If the package has been opened more than 4 week or the color of the desiccant changes, components should be dried for 10-12hr at 60 ± 5 °C
- Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
- Do not rapidly cool device after soldering.
- Components should not be mounted on warped (non coplanar) portion of PCB.
- Radioactive exposure is not considered for the products listed here in.
- Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
- This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.

• When the LEDs are in operation the maximum current should be decided after measuring the package temperature.

• LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or

more after being shipped from SSC, a sealed container with a nitrogen atmosphere should be used for storage.

- The appearance and specifications of the product may be modified for improvement without notice.
- Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.
- The slug is isolated from anode electrically.
 Therefore, we recommend that you don't isolate the heat sink.
- Attaching LEDs, do not use adhesives that outgas organic vapor.

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Handling of Silicone resin LEDs

The Z-Power LED is encapsulated with a silicone resin for the highest flux efficiency. Notes for handling:

- Avoid touching silicone resin parts especially with sharp tools such as Pincetter (Tweezers)
- Avoid leaving fingerprints on silicone resin parts.
- Silicone resin will attract dust so use covered containers for storage.
- When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that excessive mechanical pressure on the surface of the resin must be prevented.
- It is not recommend to cover the silicone resin of the LEDs with other resin (epoxy, urethane, etc)

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